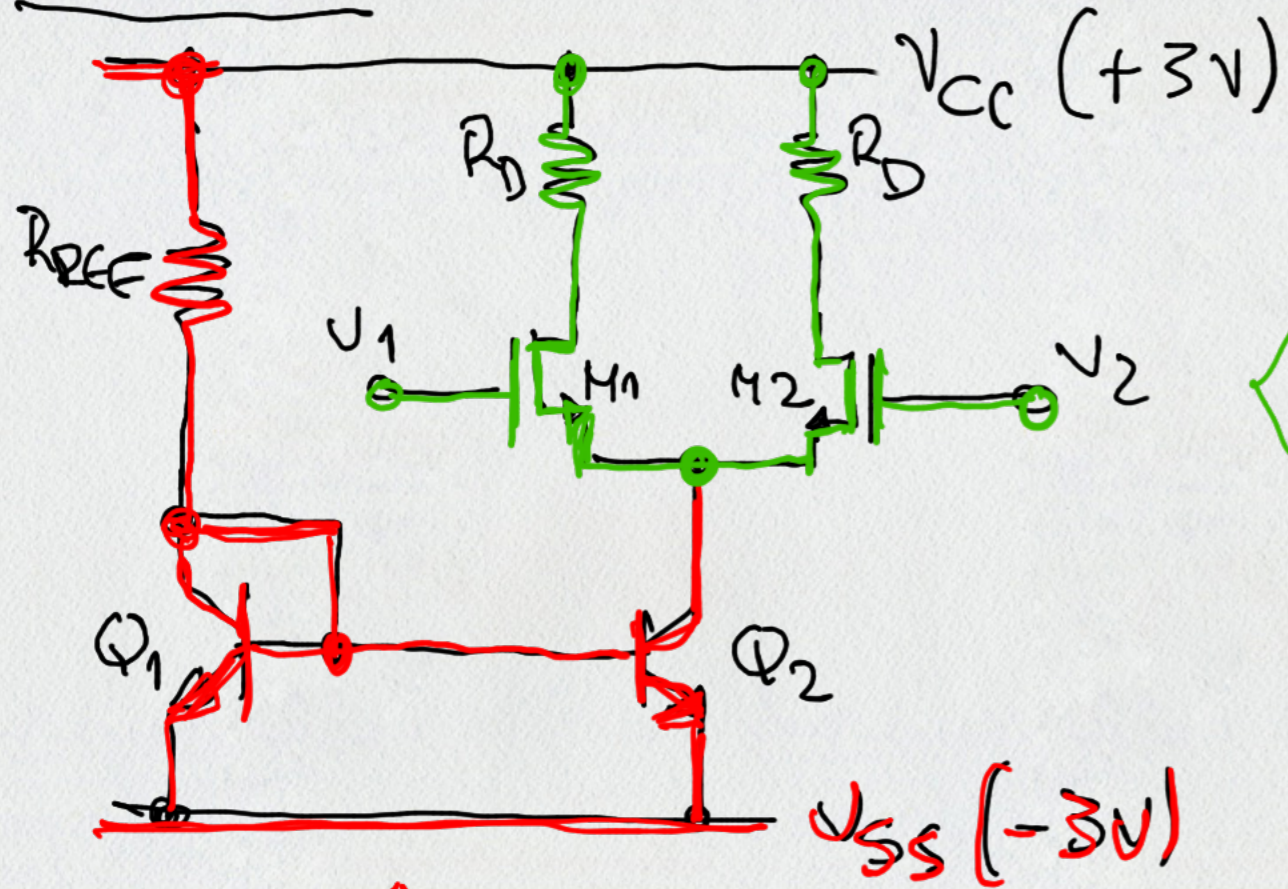


Problema 1



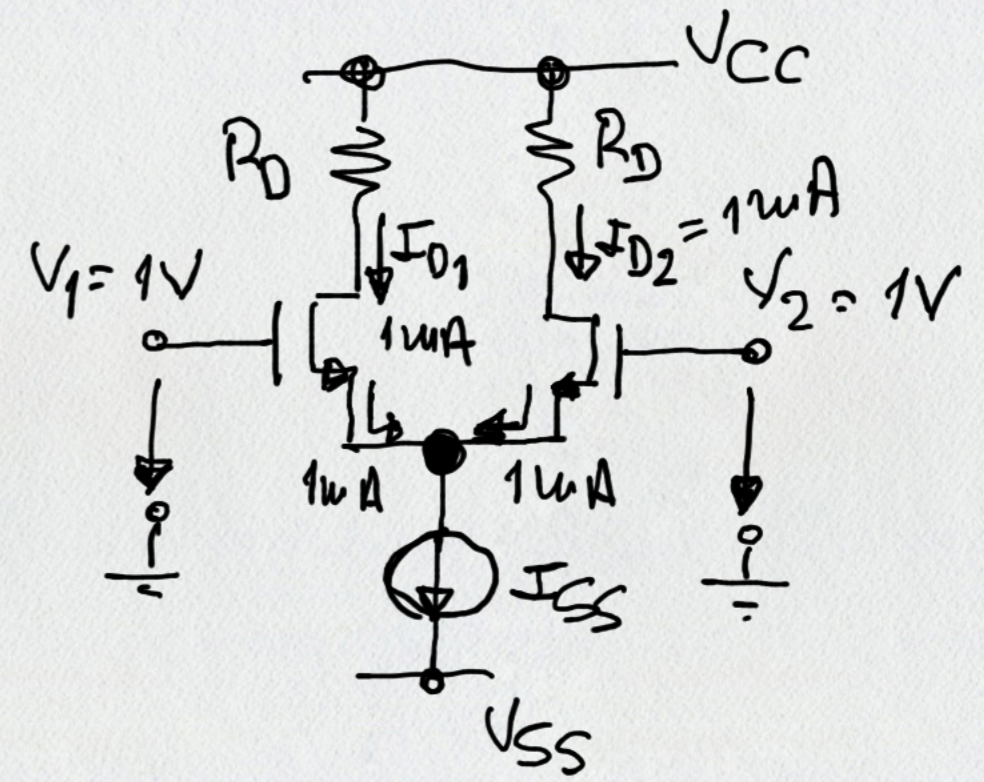
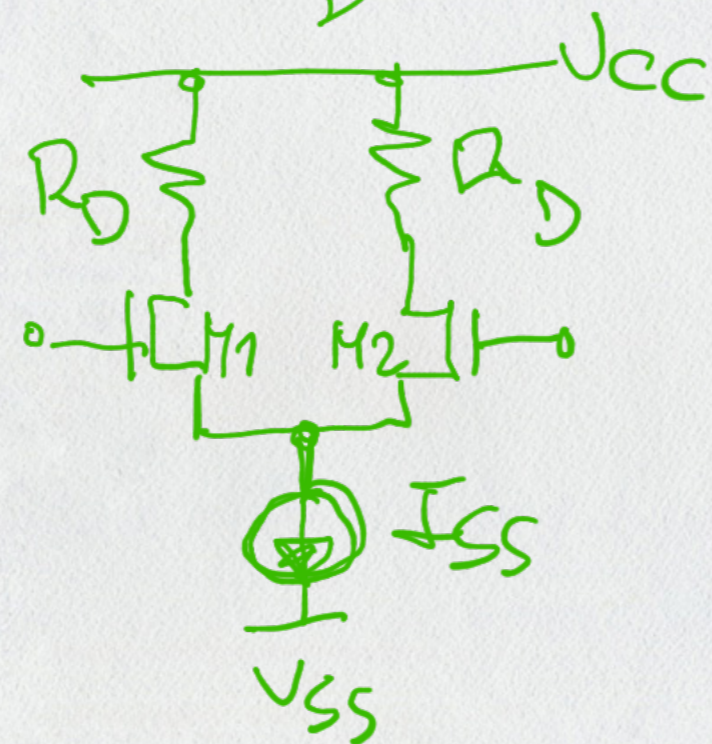
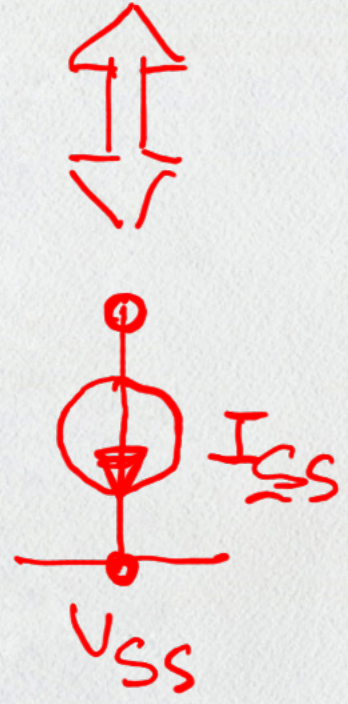
$R_D = 2\text{ k}\Omega$
Circuito

$V_{BE_{on}} = 0.7\text{ V}$
 $V_{CE_{set}} = 0.3\text{ V}$
 $V_A = 50\text{ V}$
TJB

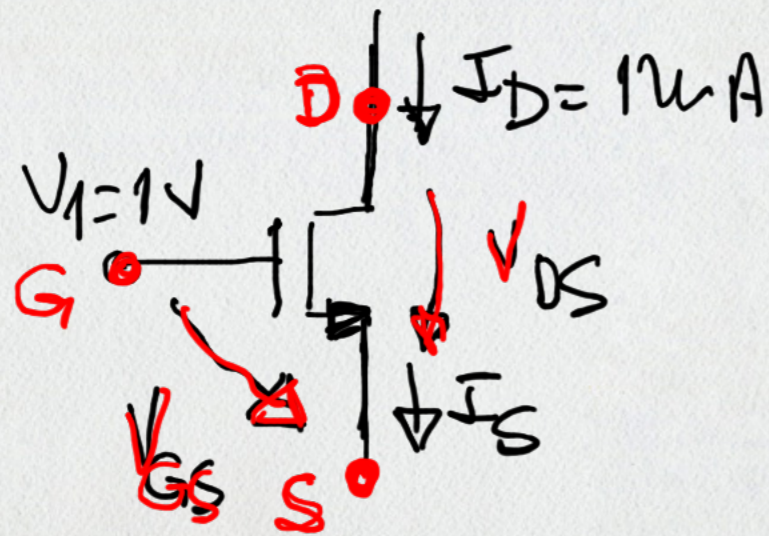
$k_n = 1\text{ }\mu\text{A}\cdot\text{V}^{-2}$
 $V_{th} = 1\text{ V}$
 $V_A = \infty$
NMOS

a) $R_{REF} = ?$

$I_{D1} = I_{D2} = 1\text{ }\mu\text{A}$
 $V_1 = V_2 = 1\text{ V}$



Temos que definir a zona de condução de M_1 e M_2 \Rightarrow $I_{SS} = 2\text{ }\mu\text{A}$
 Estão a conduzir com $I_D = 1\text{ }\mu\text{A}$ $\left\{ \begin{array}{l} \text{set.} \Rightarrow V_{DS} > V_{GS} - V_{th} \\ \text{tródo} \Rightarrow V_{DS} < V_{GS} - V_{th} \end{array} \right.$

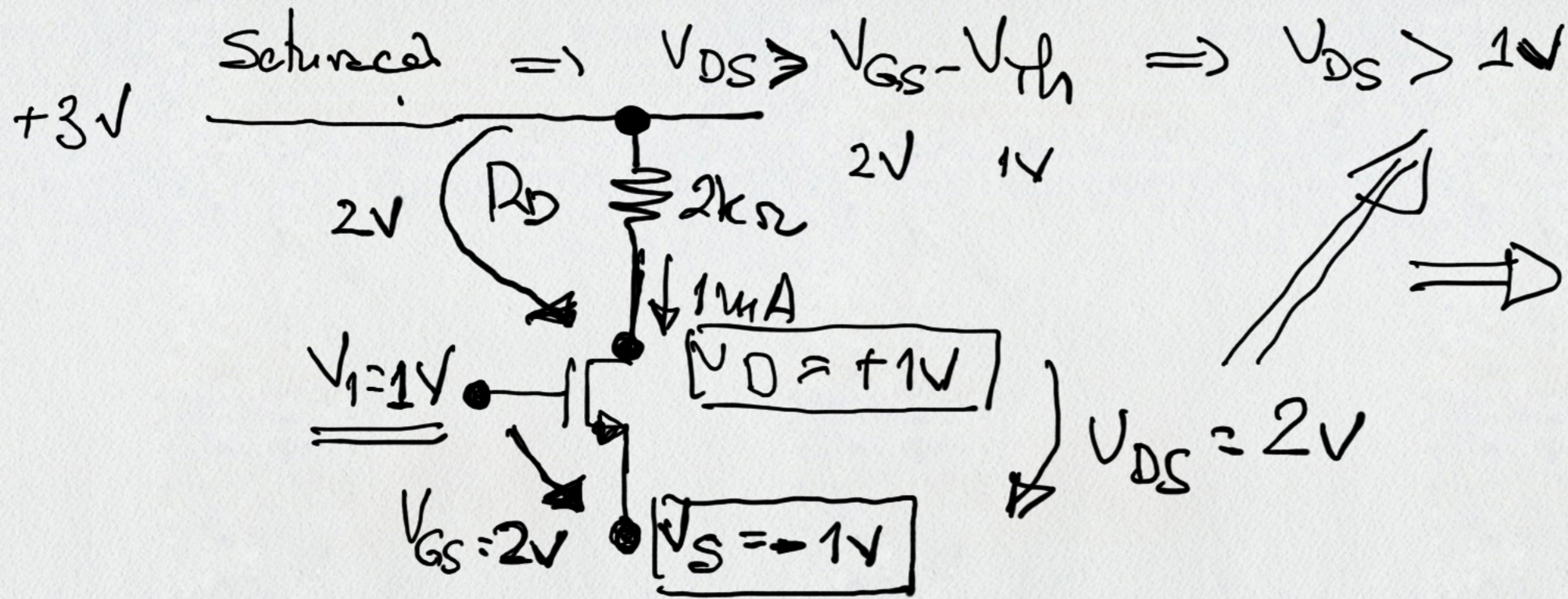


Saturated: $I_D = k_n (V_{GS} - V_{TH})^2$ (forced)

$$1\mu A = 1\mu A \cdot V^{-2} (V_{GS} - 1)^2$$

$$1V^2 = (V_{GS} - 1V)^2$$

$$\Rightarrow \boxed{V_{GS} = 1 + 1 = 2V}$$



NMOS est' em saturação

M1

$$I_{D1} = 1\mu A$$

$$V_{GS1} = 2V$$

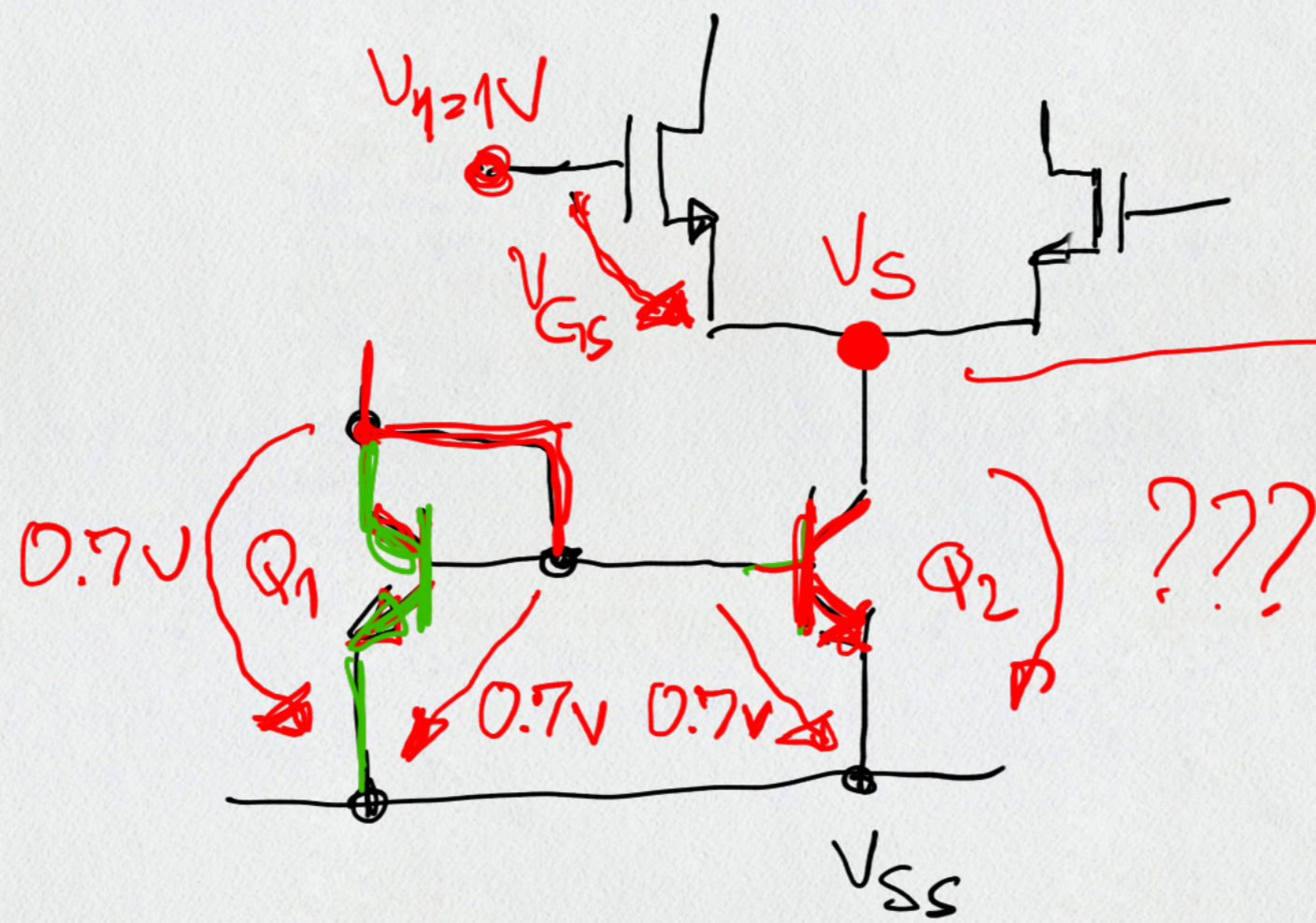
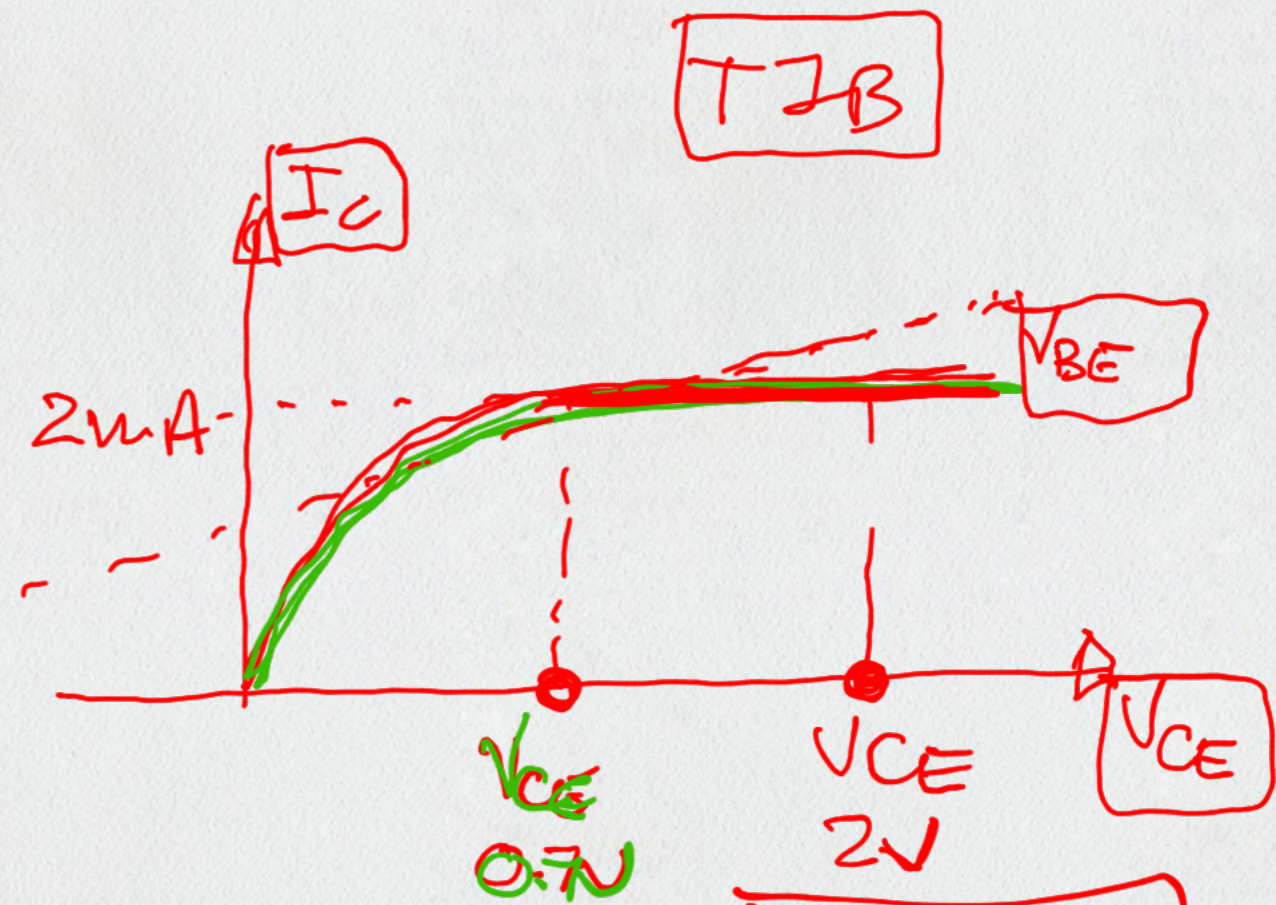
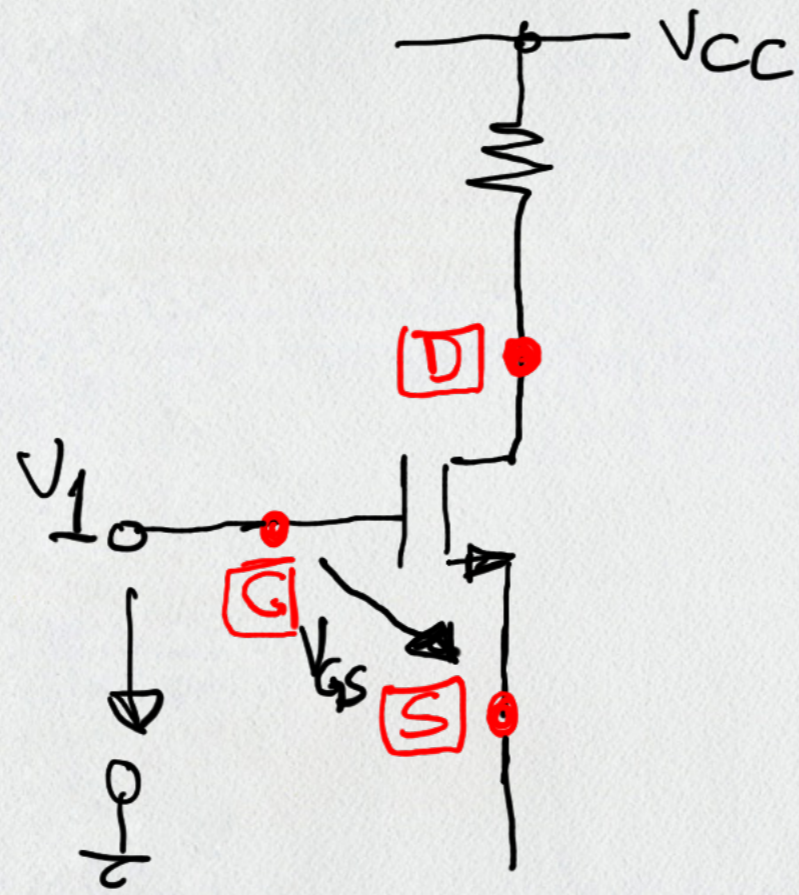
$$V_{DS1} = 2V$$

M2

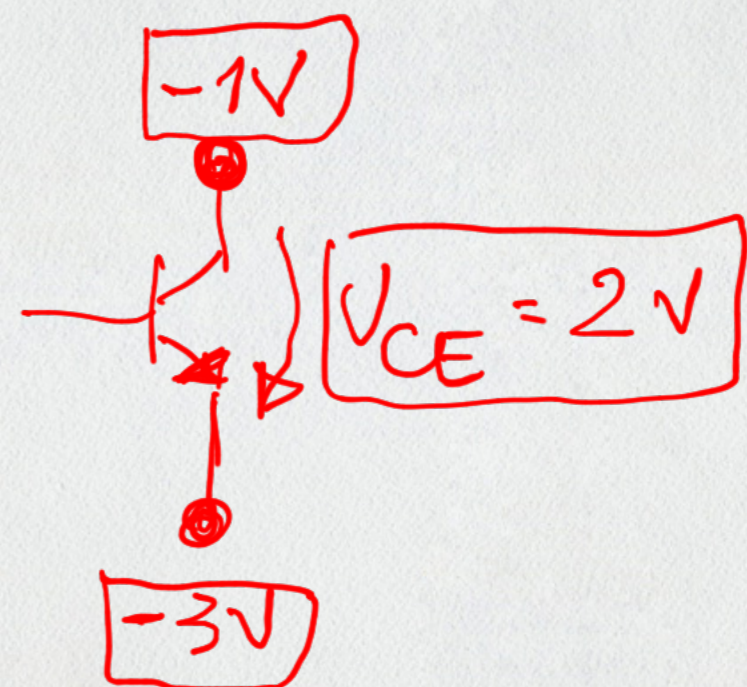
$$I_{D2} = 1\mu A$$

$$V_{GS2} = 2V$$

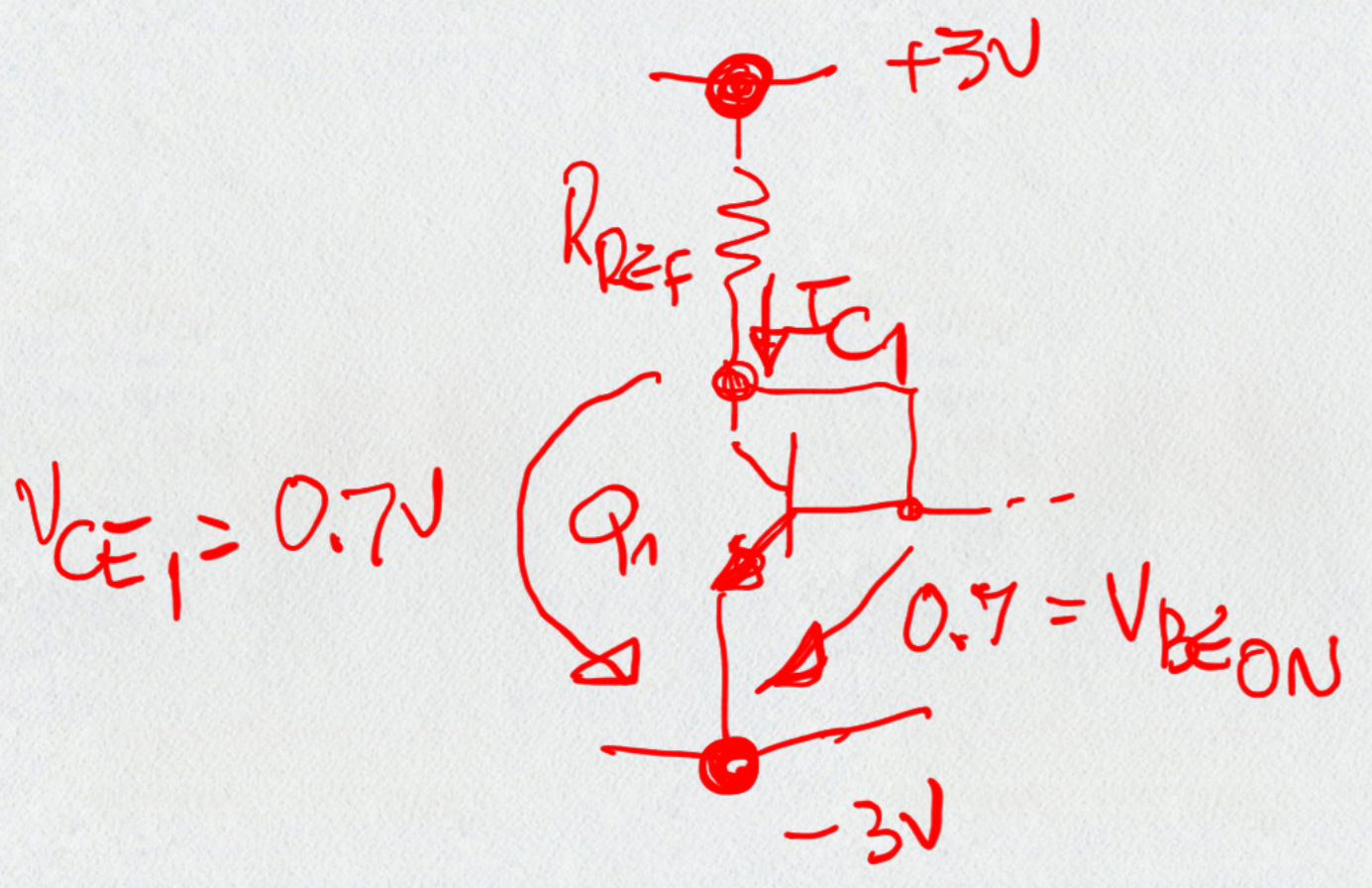
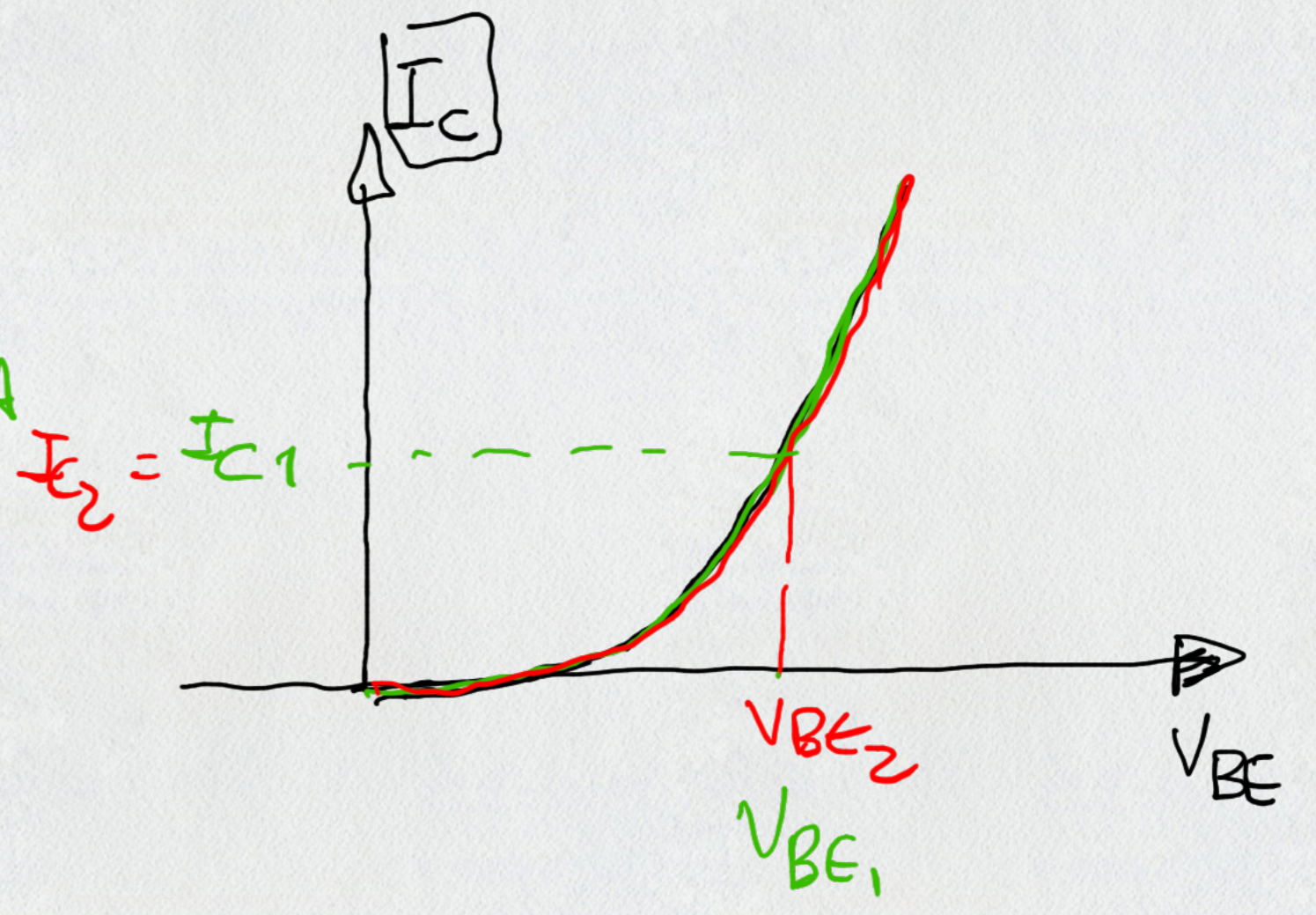
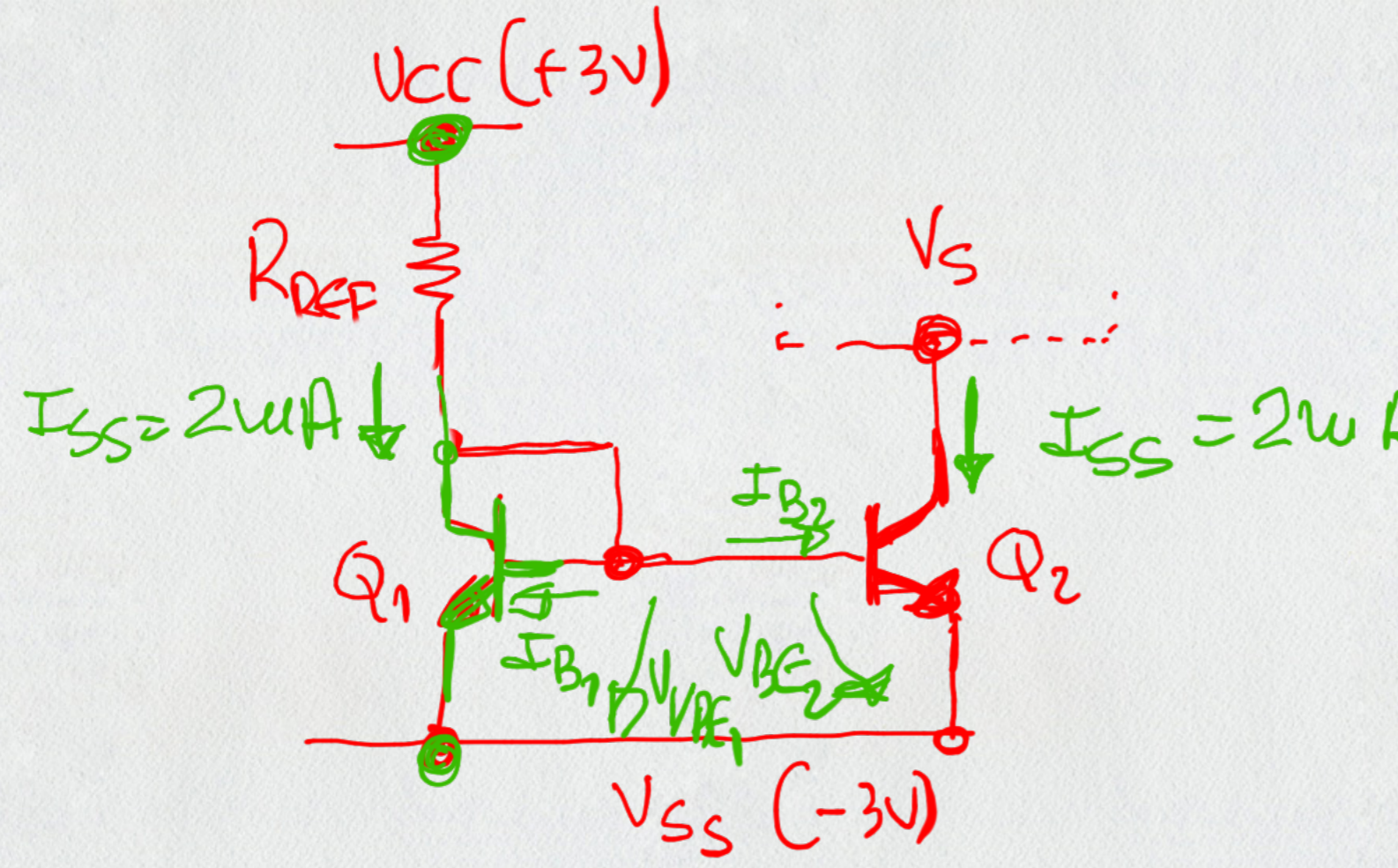
$$V_{DS2} = 2V$$



$V_{GS} = 2V \Rightarrow V_S = -1V$



???



$$V_{CC} - (V_{SS}) = R_{REF} \cdot I_{C1} + V_{CE1}$$

$$+3V - (-3V) = R_{REF} \cdot 2\mu A + 0.7V$$

$$R_{REF} = \frac{+6V - 0.7V}{2\mu A} = \frac{5.3}{2} k\Omega$$

$$R_{REF} = 2.65 k\Omega$$

b)

M1

$$I_{D1} = 1 \mu A$$

$$V_{GS1} = +2V$$

$$V_{DS1} = +2V$$

M2

$$I_{D2} = 1 \mu A$$

$$V_{GS2} = +2V$$

$$V_{DS2} = +2V$$

Q1

$$V_{BE1} = 0.7V$$

$$V_{CE1} = 0.7V$$

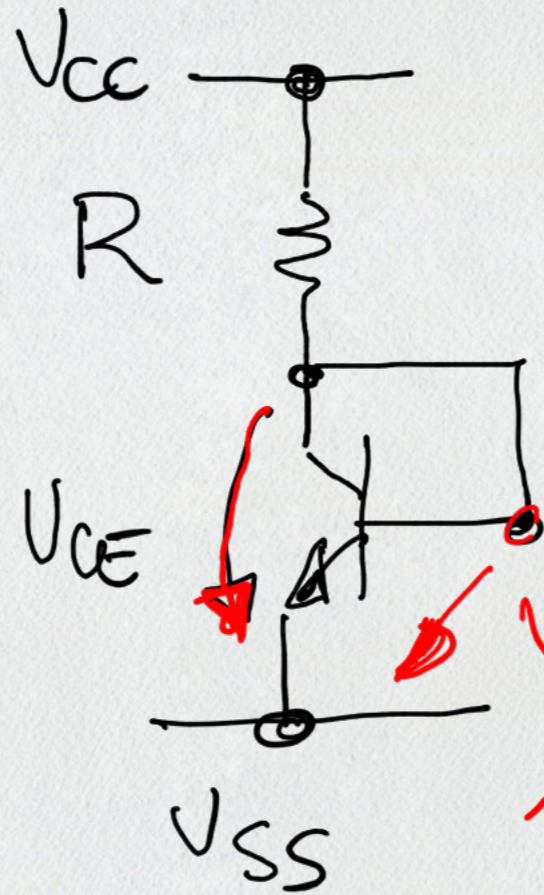
$$I_{C1} = 2 \mu A$$

Q2

$$V_{BE2} = 0.7V$$

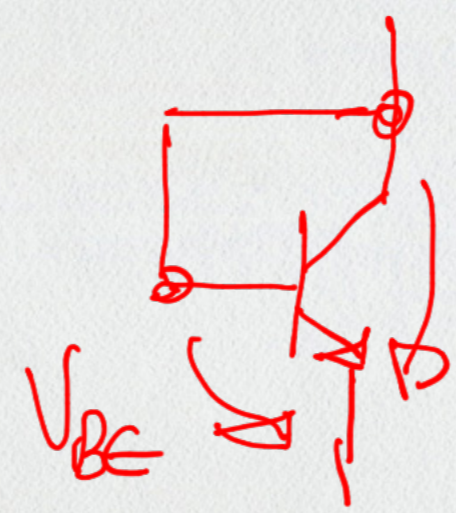
$$V_{CE2} = 2V$$

$$I_{C2} = 2 \mu A$$



~~$V_{CE} = V_{CE_{sat}}$~~

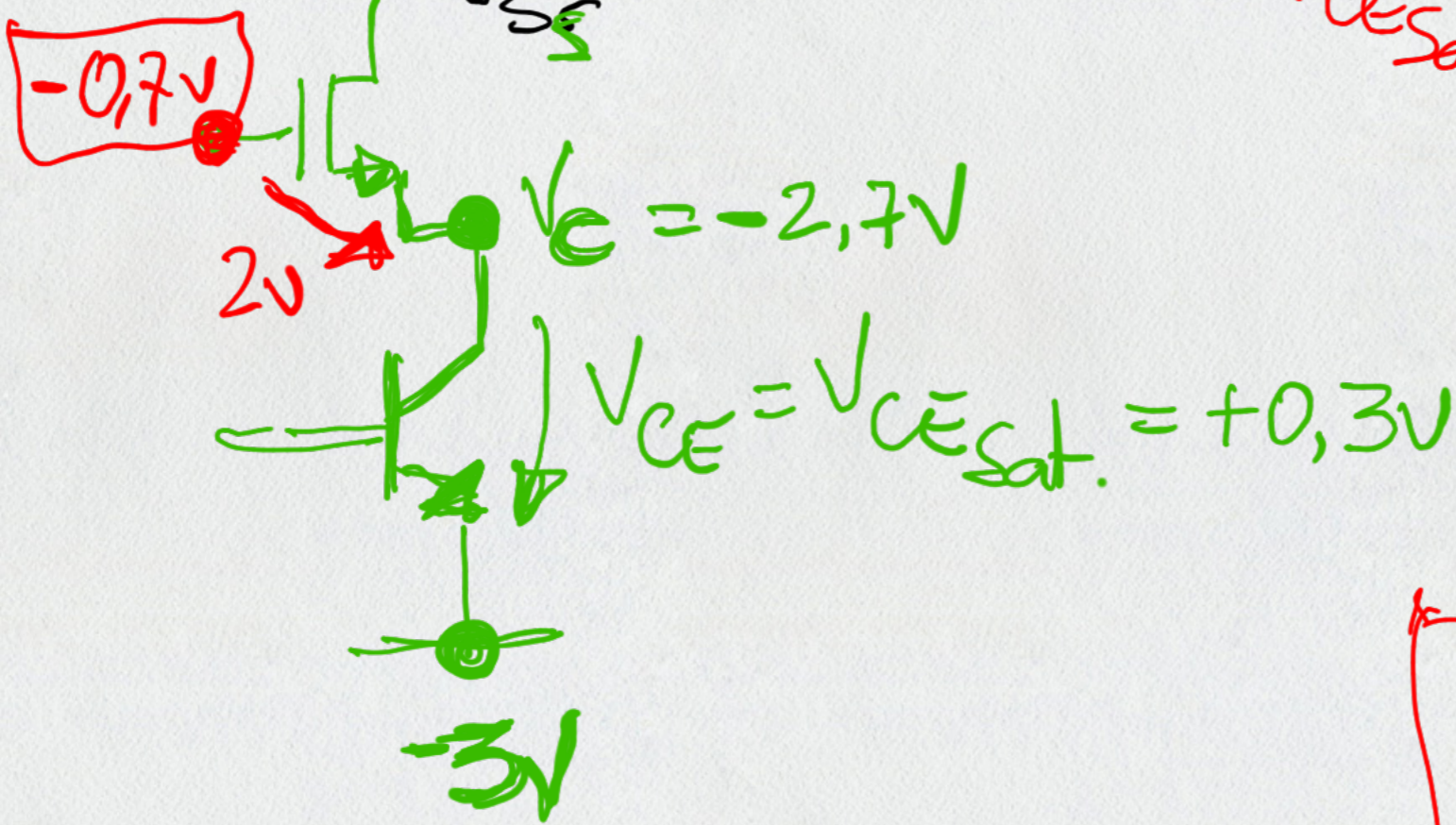
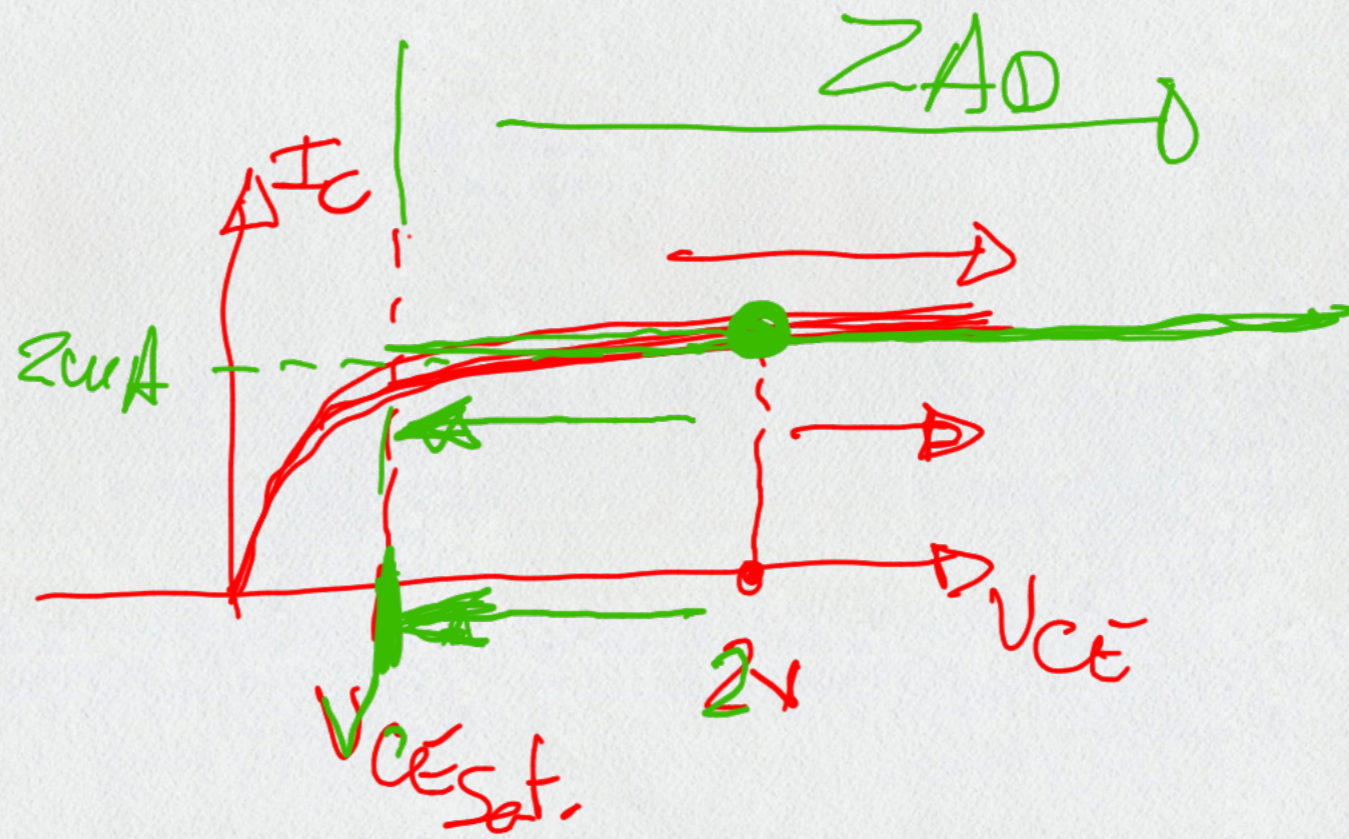
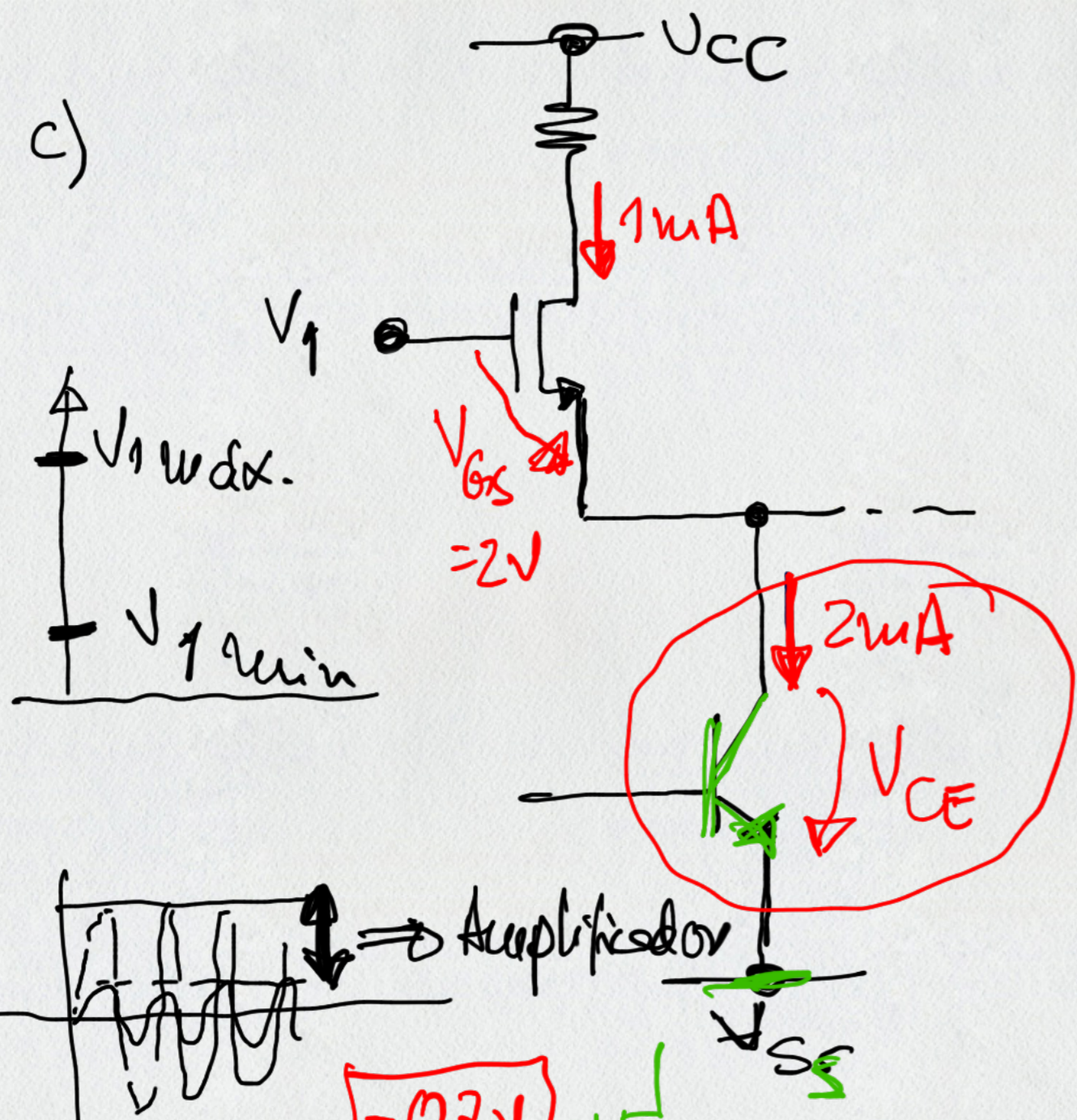
~~$V_{BE} = 0.3V$~~



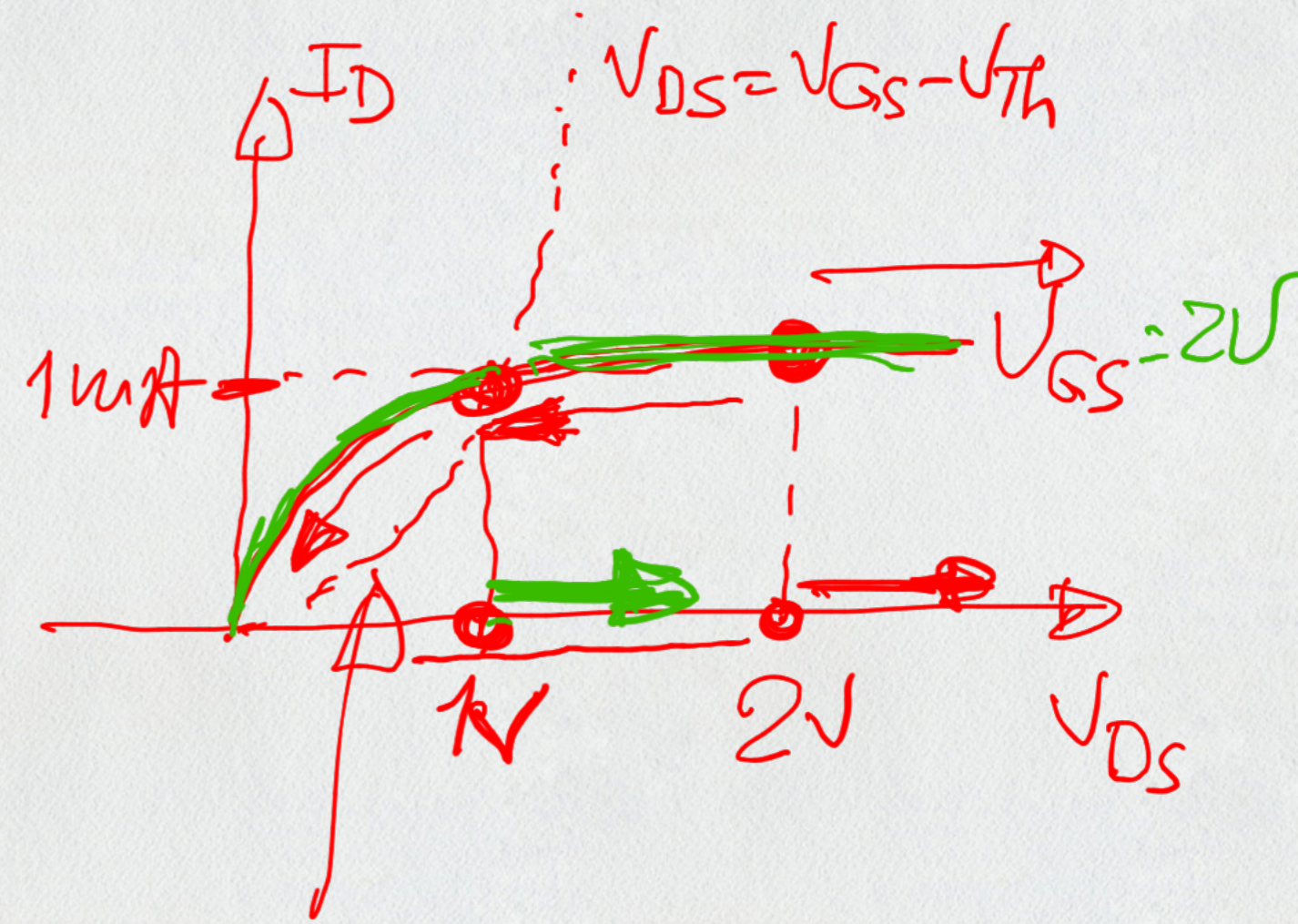
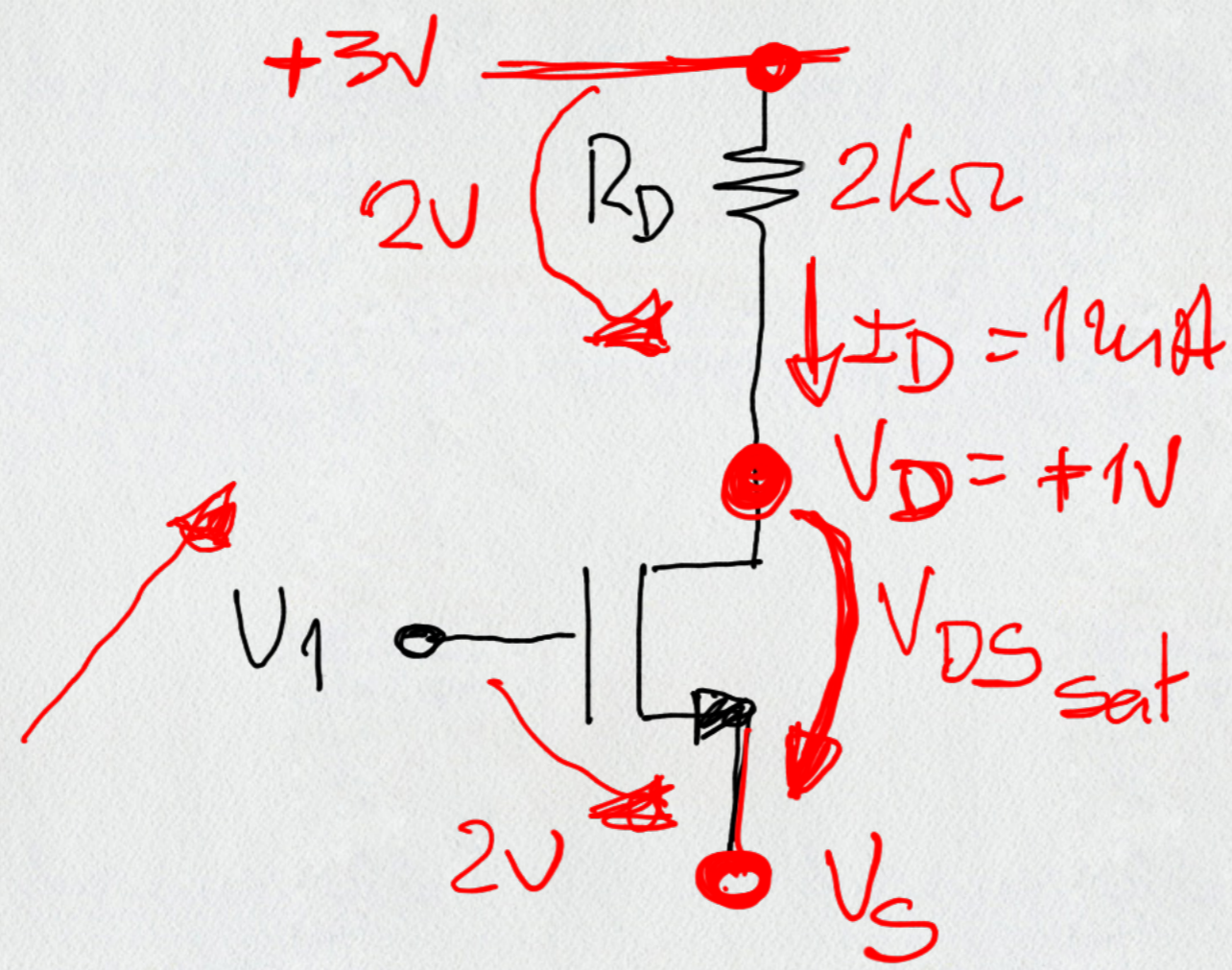
$V_{CE} = V_{BE} \Rightarrow$ TJB este ce 2AD

$V_{CE} = V_{BE} = 0.7 > 0.3$ (Sat.)

c)

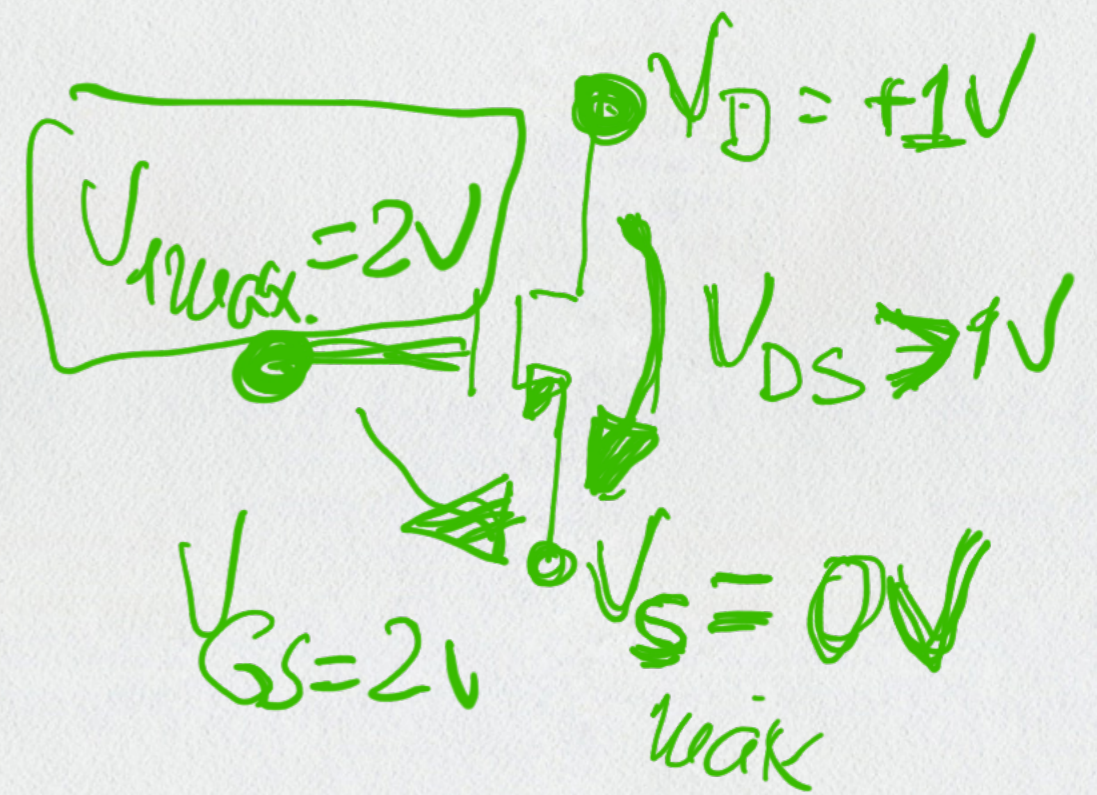
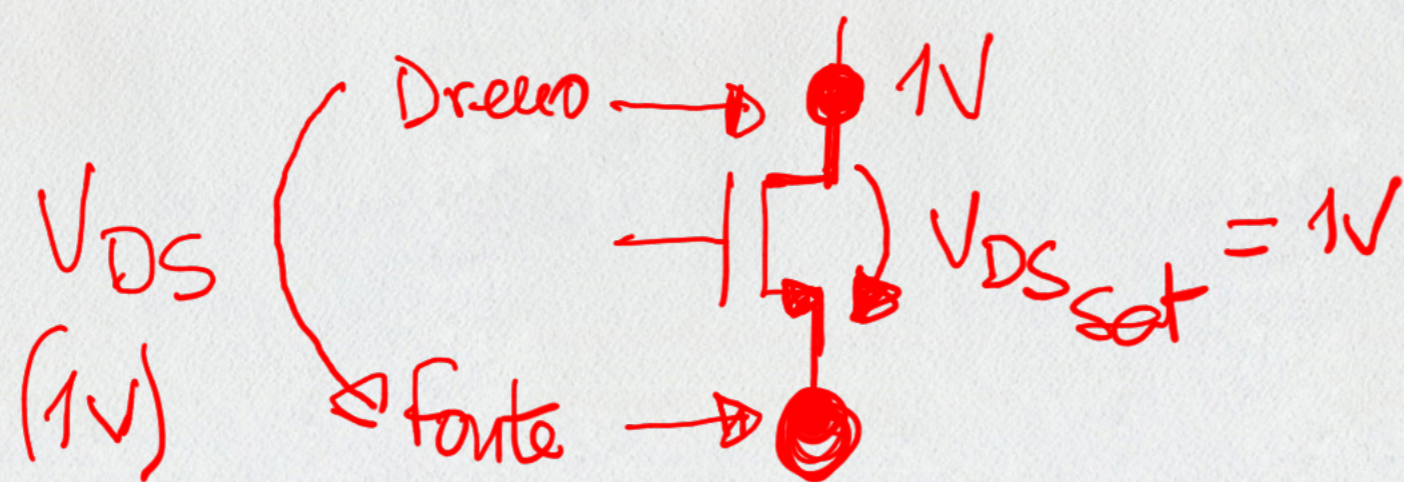


$$V_{C\text{min}} = -0,7\text{V}$$

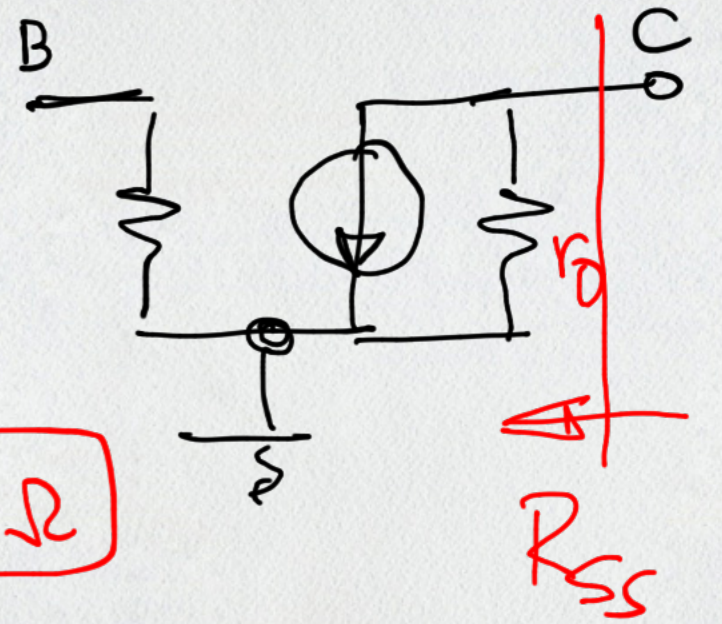
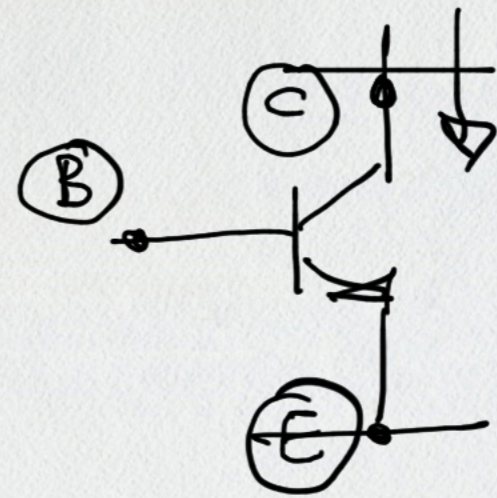
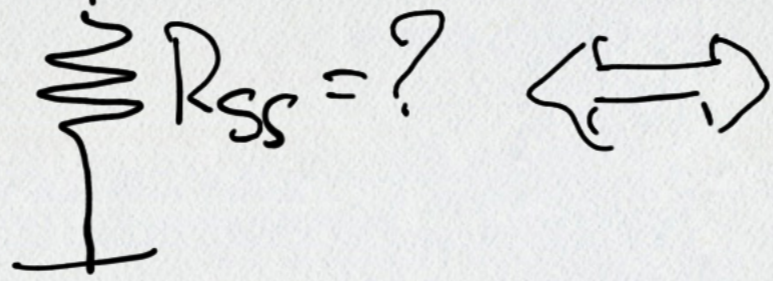
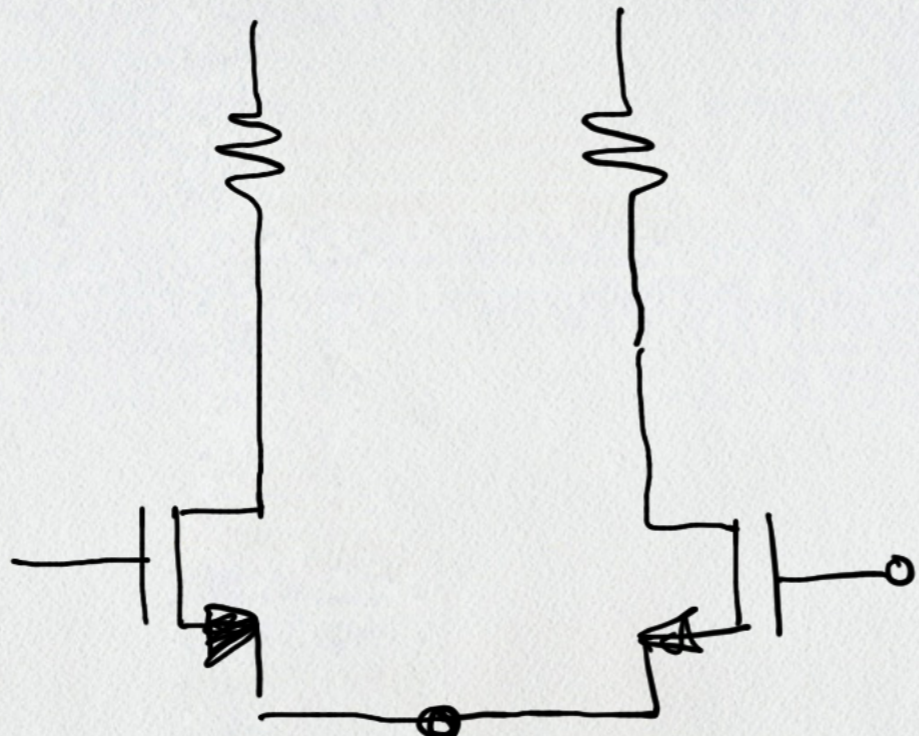


$$V_{DS_{sat}} = 2V - 1V = 1V$$

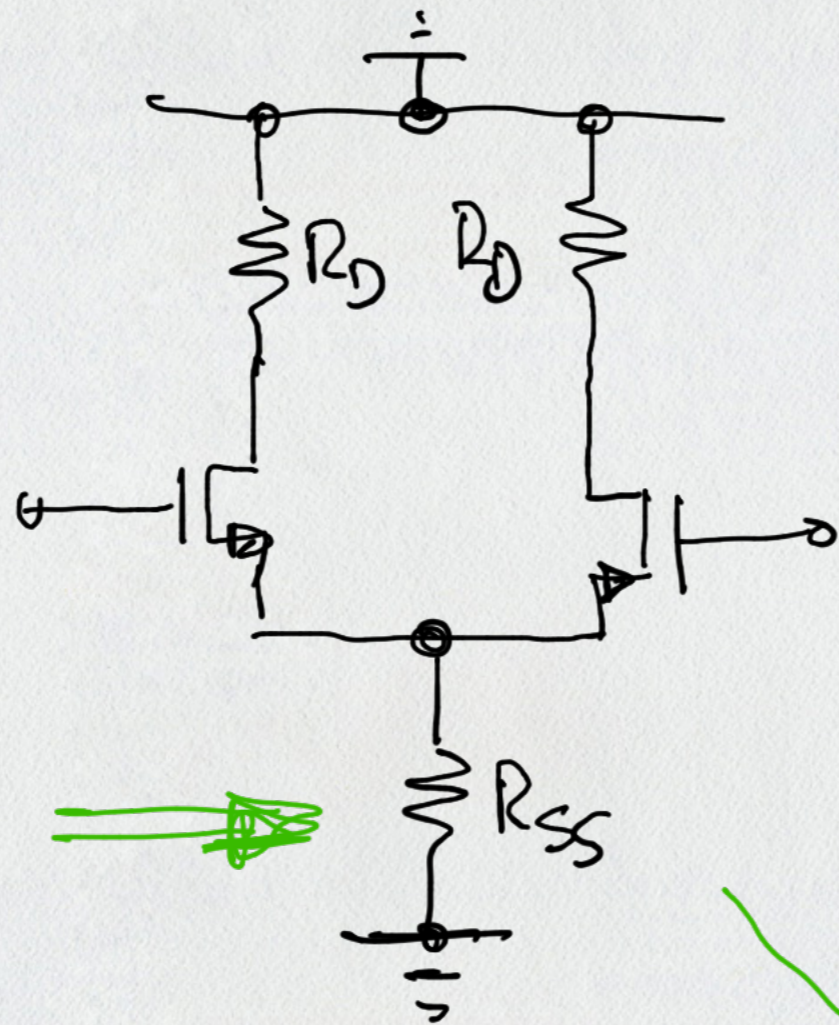
$$V_{DS} = V_{GS} - V_{TH}$$



2)

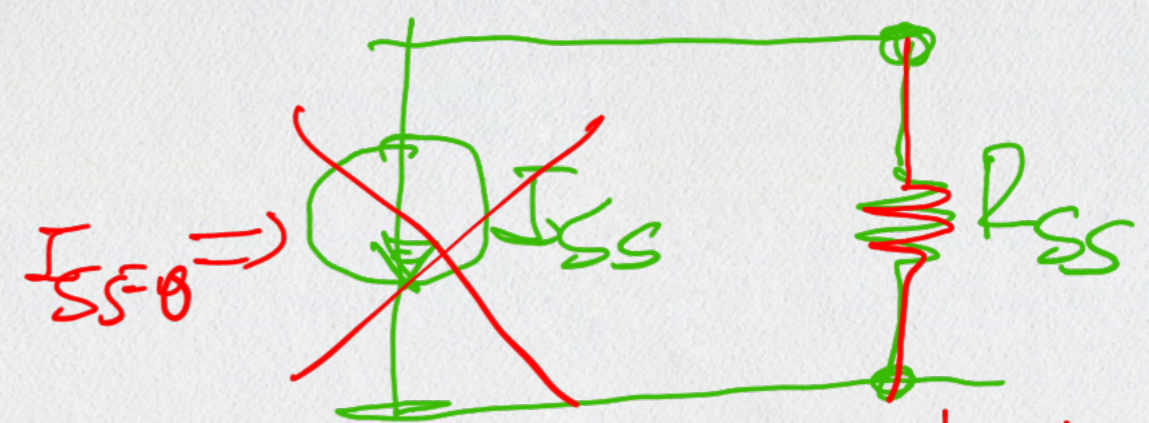


$$R_{SS} = r_o \rightarrow \frac{V_A}{I_C} = \frac{+50V}{2\mu A} = 25k\Omega$$



Esquema momental de
função fraca, anulação de cas
forte, DC

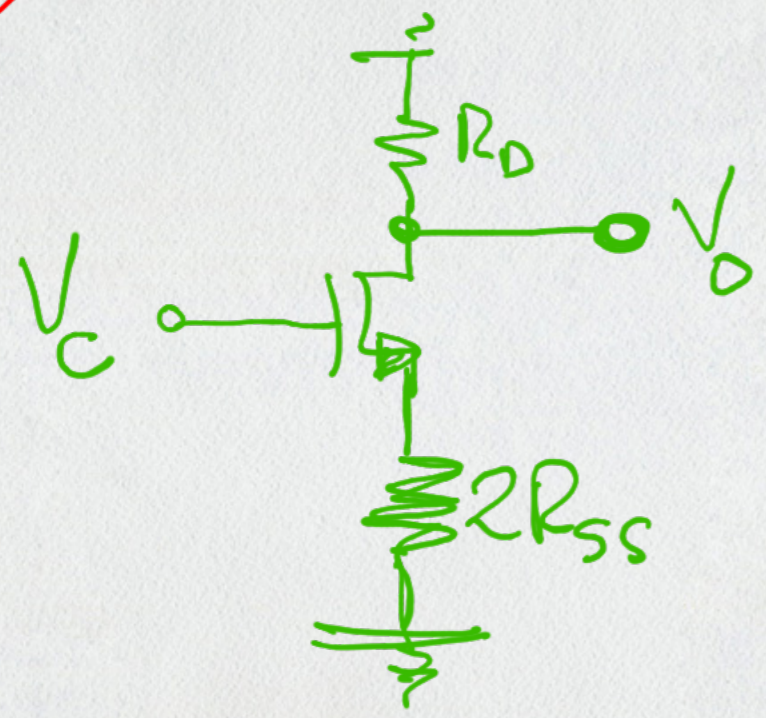
$V_{CC} = 0$
 $V_{SS} = 0$



Se a fonte for ideal, n̄ existe RSS

(d)

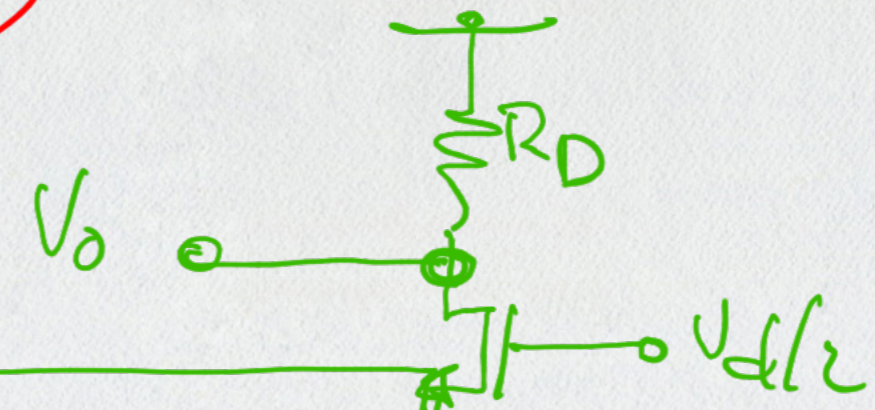
Modo Comum



$\frac{V_o}{V_c} = -\frac{R_D}{2R_{SS}}$

(e)

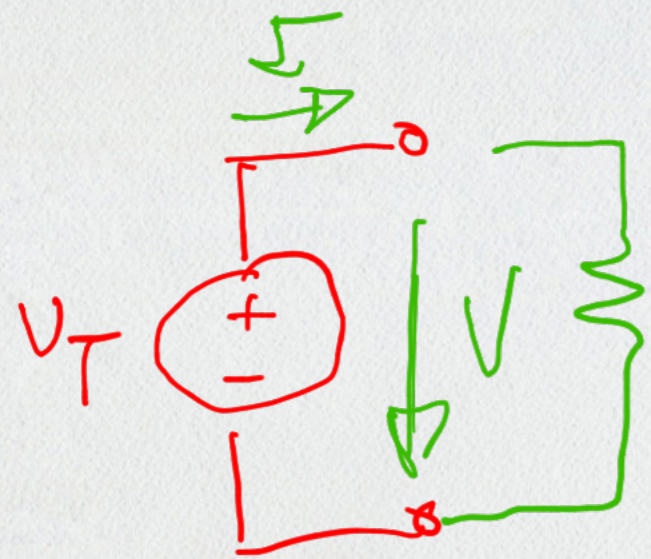
Modo Diferencial



$\frac{V_o}{(V_{d/2})} = -g_m R_D$

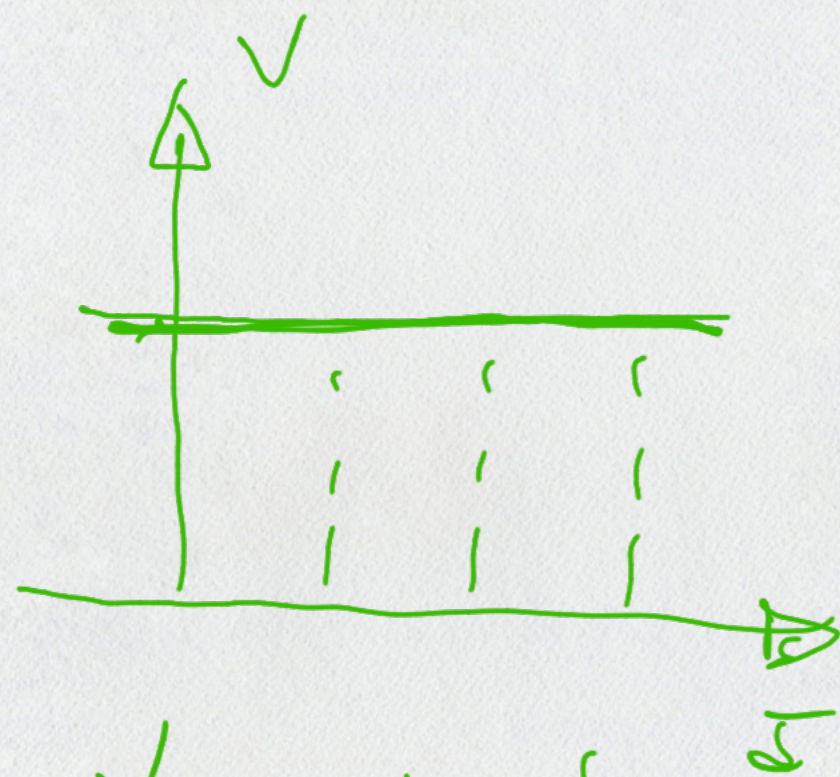
$g_m (\text{NMOS}) = 2\sqrt{k_n I_D}$

$g_m = 2 \mu S$



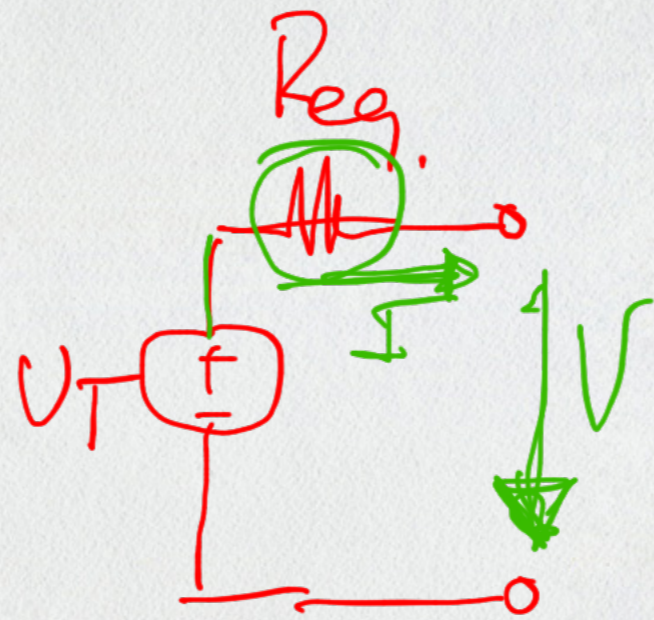
Modelo ideal

frente tension



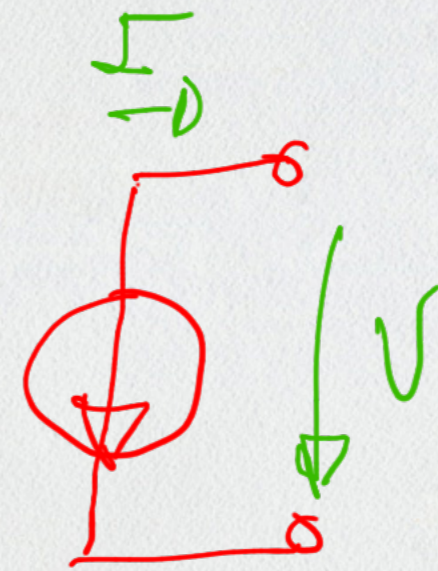
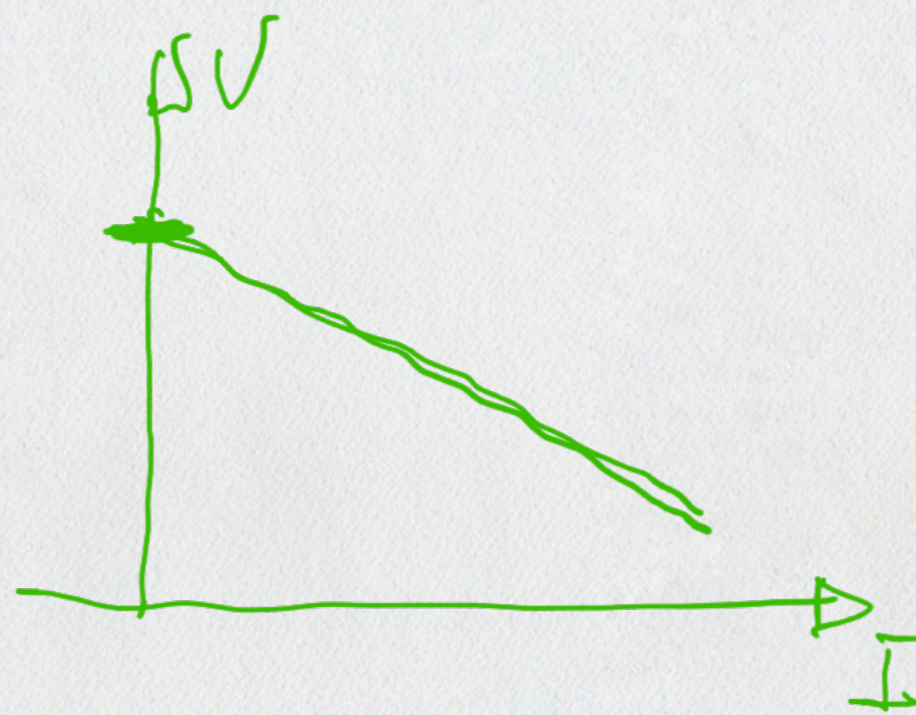
V constante

pl 99. I



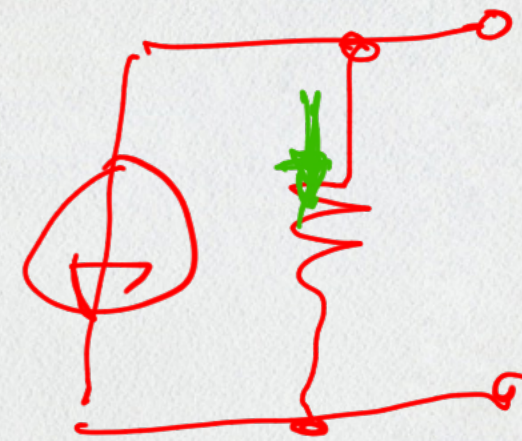
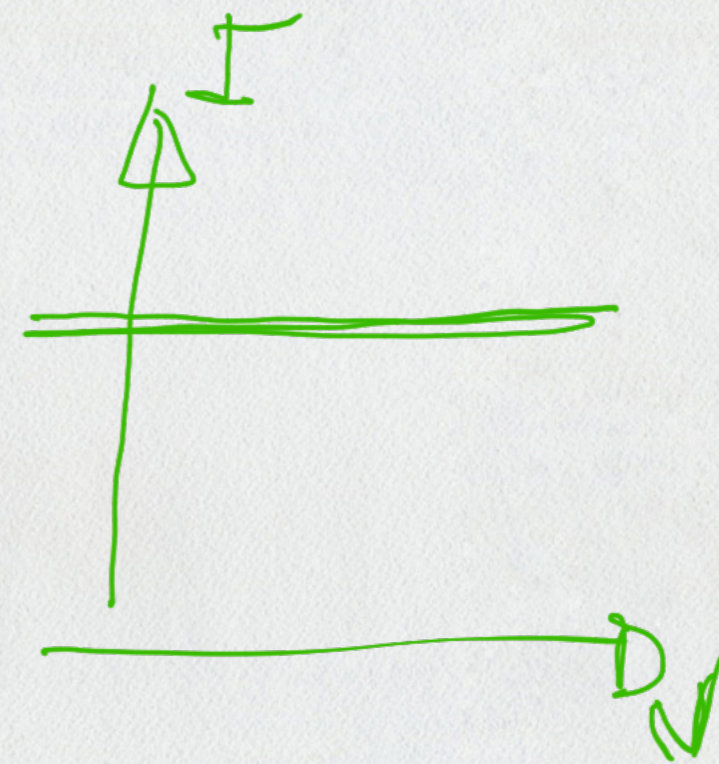
Modelo Real

frente de tension



Modelo ideal

frente de corriente



Modelo Real

frente de corriente

